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Renesas Technology Corp.
Customer Support Dept.
April 1, 2003

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Keep safety first in your circuit designs!

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Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (i) placement of substitutive, auxiliary circuits, (ii) use of nonflammable material or (iii) prevention against any malfunction or mishap.

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HVD138

Silicon Epitaxial Trench Pin Diode for Antenna Switching



ADE-208-958A (Z)

Rev.1
May 2001

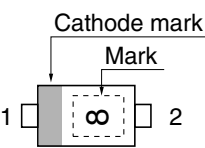
Features

- Adopting the trench structure improves low capacitance. ($C = 0.9 \text{ pF max}$)
- Low forward resistance. ($r_f = 1.1 \text{ } \Omega \text{ max}$)
- Low operation current.
- Super small Flat Package (SFP) is suitable for surface mount design.

Ordering Information

| Type No. | Laser Mark | Package Code |
|----------|------------|--------------|
| HVD138 | 8 | SFP |

Outline



1. Cathode
2. Anode

Absolute Maximum Ratings

(Ta = 25°C)

| Item | Symbol | Value | Unit |
|----------------------|--------|-------------|------|
| Reverse voltage | V_R | 30 | V |
| Forward current | I_F | 100 | mA |
| Power dissipation | Pd | 150 | mW |
| Junction temperature | Tj | 125 | °C |
| Storage temperature | Tstg | −55 to +125 | °C |

Electrical Characteristics

(Ta = 25°C)

| Item | Symbol | Min | Typ | Max | Unit | Test Condition |
|--------------------|--------|-----|-----|-----|----------|--|
| Reverse current | I_R | — | — | 10 | nA | $V_R = 25\text{ V}$ |
| Forward voltage | V_F | — | — | 0.9 | V | $I_F = 2\text{ mA}$ |
| Capacitance | C | — | — | 0.9 | pF | $V_R = 1\text{ V}$, $f = 1\text{ MHz}$ |
| Forward resistance | r_f | — | — | 1.1 | Ω | $I_F = 2\text{ mA}$, $f = 100\text{ MHz}$ |

Note: 1. Please do not use the soldering iron due to avoid high stress to the SFP package.

Main Characteristic

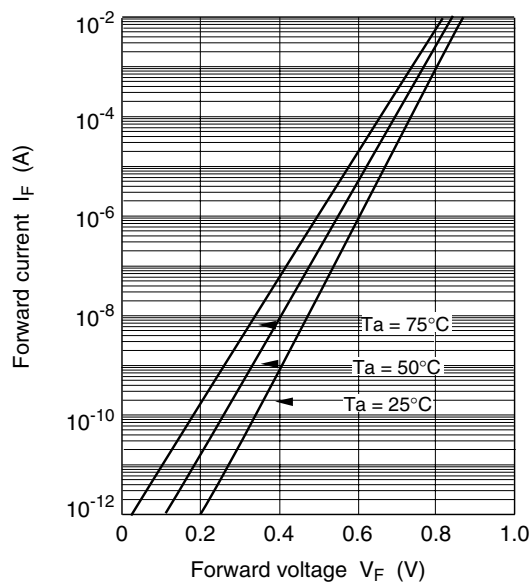


Fig.1 Forward current vs. Forward voltage

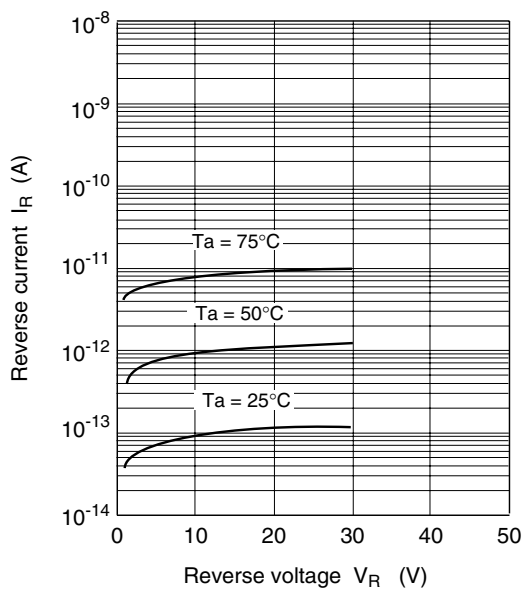


Fig.2 Reverse current vs. Reverse voltage

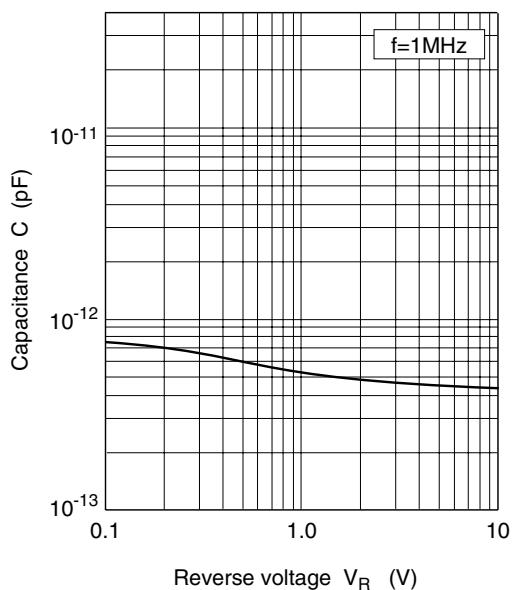


Fig.3 Capacitance vs. Reverse voltage

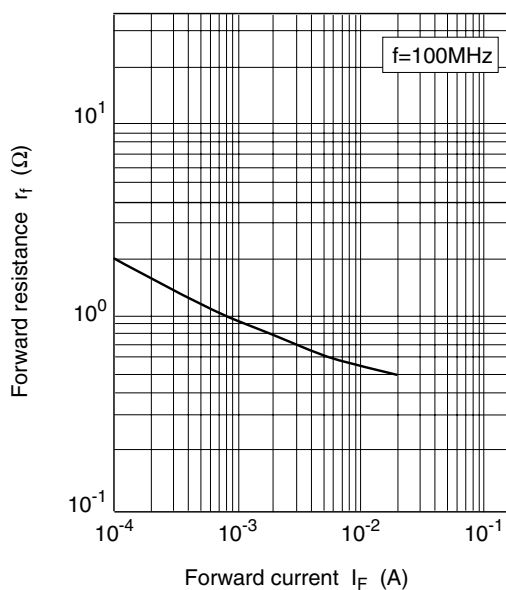


Fig.4 Forward resistance vs. Forward current

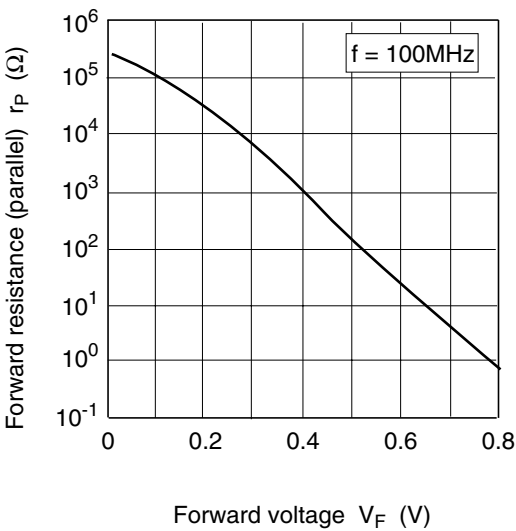
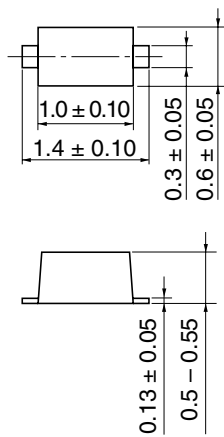


Fig.5 Forward resistance (parallel) vs. Forward voltage

Package Dimensions

As of January, 2001
Unit: mm



| | |
|------------------------|----------|
| Hitachi Code | SFP |
| JEDEC | — |
| EIAJ | — |
| Mass (reference value) | 0.0010 g |

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